

TOSHIBA LED LAMP GaP GREEN LIGHT EMISSION

TLGD262

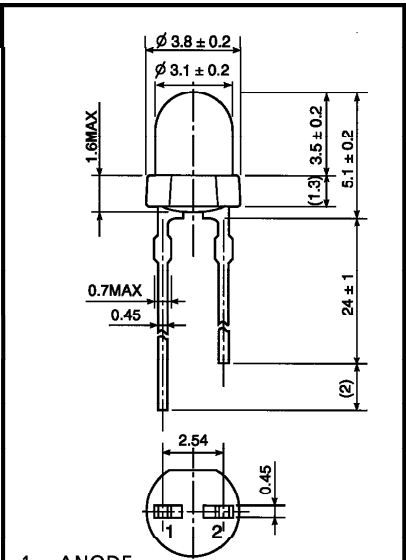
PANEL CIRCUIT INDICATOR

- $\phi 3.1\text{mm}$
- Colorless Transparent Lens
- Low Drive Current, High Intensity Green Light Emission
Recommended Forward Current : $I_F=10\sim15\text{mA}$ (DC)
- All Plastic Molded Lens, Provides an Excellent ON-OFF Contrast Ratio
- Fast Response Time, Capable of Pulse Operation.
- Capable of CMOS Driving
- Wide Radiation Pattern : Suitable for Backlighting
- Application : OA / AV Equipment
Automotive Use

MAXIMUM RATINGS (Ta = 25°C)

CHARACTERISTIC	SYMBOL	RATING	UNIT
Forward Current (DC)	I_F	40	mA
Reverse Voltage	V_R	4	V
Power Dissipation	P_D	120	mW
Operating Temperature Range	T_{opr}	-30~85	°C
Storage Temperature Range	T_{stg}	-40~120	°C

Unit in mm



- 1. ANODE
- 2. CATHODE

JEDEC	—
EIAJ	—
TOSHIBA	4-3H1

Weight : 0.14g

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ELECTRO-OPTICAL CHARACTERISTICS (Ta = 25°C)

CHARACTERISTIC		SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Forward Voltage		V_F	$I_F = 20\text{mA}$	—	2.15	2.8	V
Reverse Current		I_R	$V_R = 4\text{V}$	—	—	5	μA
Luminous Intensity	TLGD262	I_V	$I_F = 20\text{mA}$ (Note)	15.3	50	—	mcd
	TLGD262 (KL)			15.3	—	73.6	
	TLGD262 (LM)			27.2	—	129	
Peak Emission Wave Length		λ_p	$I_F = 20\text{mA}$	—	567	—	nm
Spectral Line Half Width		$\Delta\lambda$	$I_F = 20\text{mA}$	—	25	—	nm

(Note) Rank selection carried out under next standard range respectively, although it needs $\pm 15\%$ additional for guaranteed limits.

K : 18-36mcd L : 32-64mcd M : 56-112mcd

Each rank products is classified by package unit, and (KL) includes K and L.
(LM) includes L and M.

PRECAUTION

Please be careful of the followings.

- Soldering temperature : 260°C MAX. Soldering time : 3s MAX.
(Soldering portion of lead : up to 2mm from the body of the device)
- If the lead is formed, the lead should be formed up to 5mm from the body of the device without forming stress to the resin. Soldering should be performed after lead forming.

